

# COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

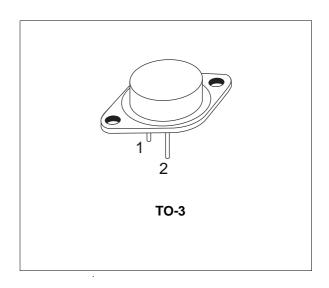
#### **APPLICATIONS**

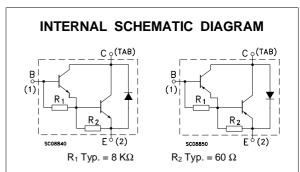
 LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

#### **DESCRIPTION**

The 2N6284 is a silicon epitaxial-base NPN power transistor in monolithic Darlington configuration mounted in Jedec TO-3 metal case. It is inteded for general purpose amplifier and low frequency switching applications.

The complementary PNP types is 2N6287.





### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit	
		NPN	2N6284		
		PNP	2N6287		
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)		100	V	
Vceo	Collector-Emitter Voltage (I <sub>B</sub> = 0)		100	V	
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)		5	V	
Ic	Collector Current		20	А	
I <sub>CM</sub>	Collector Peak Current		40	Α	
lΒ	Base Current		0.5	Α	
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C		160	W	
T <sub>stg</sub>	Storage Temperature		-65 to 200	°C	
Tį	Max. Operating Junction Temperature	200	°C		

For PNP types voltage and current values are negative.

December 2000 1/4

## THERMAL DATA

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

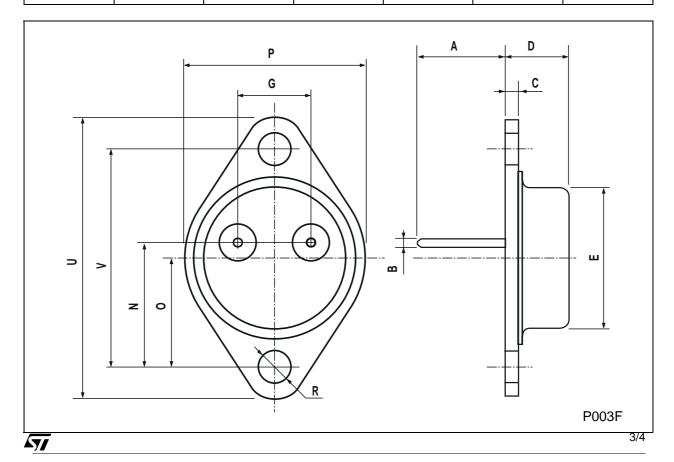
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CEV</sub>	Collector Cut-off	V <sub>CE</sub> = rated V <sub>CEO</sub>			0.5	mΑ
	Current ( $V_{BE} = -1.5V$ )	$V_{CE}$ = rated $V_{CEO}$ $T_c$ = 150 $^{\circ}$ C			5	mΑ
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 50 V			1	mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_C = 0)$	V <sub>EB</sub> = 5 V			2	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 100 mA	100			V
V <sub>CE(sat)</sub> *	Collector-Emitter	I <sub>C</sub> = 10 A I <sub>B</sub> = 40 mA			2	V
	Saturation Voltage	$I_C = 20 \text{ A}$ $I_B = 200 \text{ mA}$			3	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 20 A I <sub>B</sub> = 200 mA			4	V
$V_{BE}*$	Base-Emitter Voltage	$I_C = 10 \text{ A}$ $V_{CE} = 3 \text{ V}$			2.8	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 10 A V <sub>CE</sub> = 3 V	750		18000	
		$I_C = 20 \text{ A}$ $V_{CE} = 3 \text{ V}$	100			
h <sub>fe</sub>	Small Signal Current Gain	$I_C = 3 \text{ A}$ $V_{CE} = 10 \text{ V}$ $f = 1 \text{KHz}$	300			
C <sub>CBO</sub>	Collector Base	I <sub>E</sub> = 0 V <sub>CB</sub> = 10 V f = 100KHz				
	Capacitance	for NPN types			400	pF
	duration 200 and duty avaled	for PNP types			600	pF

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

2/4

# **TO-3 MECHANICAL DATA**

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	11.00		13.10	0.433		0.516	
В	0.97		1.15	0.038		0.045	
С	1.50		1.65	0.059		0.065	
D	8.32		8.92	0.327		0.351	
Е	19.00		20.00	0.748		0.787	
G	10.70		11.10	0.421		0.437	
N	16.50		17.20	0.649		0.677	
Р	25.00		26.00	0.984		1.023	
R	4.00		4.09	0.157		0.161	
U	38.50		39.30	1.515		1.547	
V	30.00		30.30	1.187		1.193	



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2000 STMicroelectronics – Printed in Italy – All Rights Reserved
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

http://www.st.com

4/4